What Is Claimed Is:

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- - a Thin-Film Transistor;
- a data line coupled to a drain #lectrode of the Thin-Film Transistor;
- a scanning line coupled to a $/\!\!/$ gate electrode of the Thin-Film Transistor and crossed to $\!\!\!/$ the data line to form a plurality of rectangular pixels in matrix;
- a pixel electrode formed at $\!\!/\!\!/\!\!/\,$ each of the pixels and coupled to a source electrode of the Thin-Film Transistor; and
- a sustaining electrode coup $\rlap/\!\!/$ ed to the pixel electrode, disposed on the pixel electrode and next to the data line and coplanar with the source effectrode.
- 2. The Thin-Film Transistor array structure as claimed in Claim 1, wherein a patter# constructed by the sustaining electrode, the source ele ϕ trode and the data line is designed as a mask.
 - 3. The Thin-Film Trans∦stor array structure as claimed 1 in Claim 1, wherein the #ustaining electrode is formed in 2 an H-shaped pattern.
- 4. The Thin-Film Transistor array structure as claimed 1 in Claim 1, wherein the pixel electrode is coupled to the 2 pixel electrode via a contact hole. 3
- 5. The Thin-Film Transistor array structure as claimed 1 in Claim 1, wherein the sustaining electrode is coupled to 2 the pixel electrode $v \not\parallel$ a a contact hole. 3
- A Thin-Film Transistor array structure, comprising: 1

- 2 a Thin-Film Transistor;
- a data line coupled to $\!\!\!/\!\!\!/$ a drain electrode of the Thin-3 Film Transistor; 4
- a scanning line coupled to a gate electrode of the 5 Thin-Film Transistor and crossed to the data line to form a 6 plurality of rectangular pixels in matrix; and 7
- a pixel elect fode formed at each of the pixels and 8 coupled to a source electrode of the Thin-Film Transistor 9 via a contact pole, disposed on the source electrode which 10 is extended $t\not\!\!\!/$ the region where the pixel electrode is next 11 12 to the data/line.
 - 7. The Thin-Film Transistor array structure as claimed in Claim 6, wherein a pattern constructed by the source electrode and the data line is designed as a mask.
- ٠ 1 ا^{ائور} 8. The Thin-Film Transistor array structure as claimed in Claim 6, wherein the source electrode is formed in a U-**FIJ 2** shaped pattern.
 - 9. The Thin-Film Transistor array structure as claimed 1 in Claim 6, wherein the electrode is coupled to the 2 pixel electrode via a contact hole. 3



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